NSN 5961-01-410-2826

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-410-2826 **Inclosure Material:** Metal **Overall Length:** 1.772 inches Overall Diameter: 0.667 inches **End Application:** Ac-130h, mc-130h, ec-130e, hc-130 aircraft. **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-65 **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.676 inches and 0.684 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1100.0 nonrepetitive peak reverse voltage and 1000.0 repetitive peak reverse voltage and 1000.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 63.00 amperes forward current, total rms horsepower metric and 40.00 amperes forward current, total rms universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Test Data Document:** 20418-es4631 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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